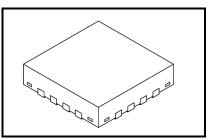


Toshiba CDMOS Integrated Circuit Silicon Monolithic

TC78H653FTG

1.8-V Dual H-bridge driver IC

The TC78H653FTG is a dual H-bridge driver IC for one or two DC brushed motors or one Stepping motor which incorporates DMOS with low ON resistance in output transistors. The TC78H653FTG has selectable forward, reverse, stop or brake mode. Over current detection, thermal shutdown, and under voltage lockout functions are implemented. The device is housed in a compact QFN-16 3.0 mm×3.0 mm package.



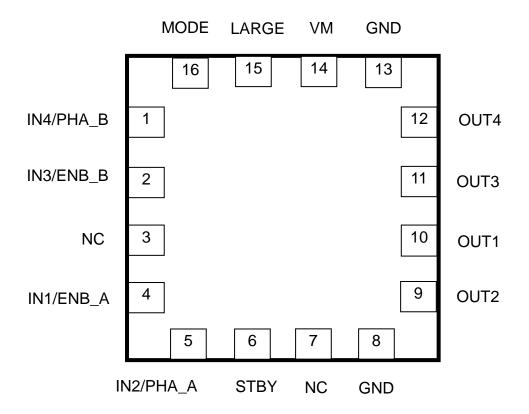
P-VQFN16-0303-0.50-001 Weight: 0.02 g (typ.)

Features

- Power supply maximum voltage: 8.0 V
- Power supply operating voltage: 1.8 V to 7.5 V
- Brushed motor output current ratings (DC)
 - 4.0A (max) in Large mode
 - 2.0A (max) in Small mode
- Brushed motor output current ratings (Peak)
 5.0A (max) at 10 ms or less in Large mode
 2.5A (max) at 10 ms or less in Small mode
 - Stepping motor output current ratings (DC)
 - 2.0A (DC)
 - 2.5A (peak)
- Output ON resistance
 - 0.11Ω (typ.) (T_a = 25 °C, Sum of upper and lower side, V_M = 5.0 V, Large mode) 0.22Ω (typ.) (T_a = 25 °C, Sum of upper and lower side, V_M = 5.0 V, Small mode)
- Built-in standby function: Consumption current 0 µA (typ.)
- Built-in cross conduction protection circuit
- Built-in over current detection (ISD), thermal shutdown (TSD), and under voltage lockout (UVLO)
- Selectable Forward / Reverse / Stop / Brake modes
- Package: P-VQFN16-0303-0.50-001(3.0 mm×3.0 mm)

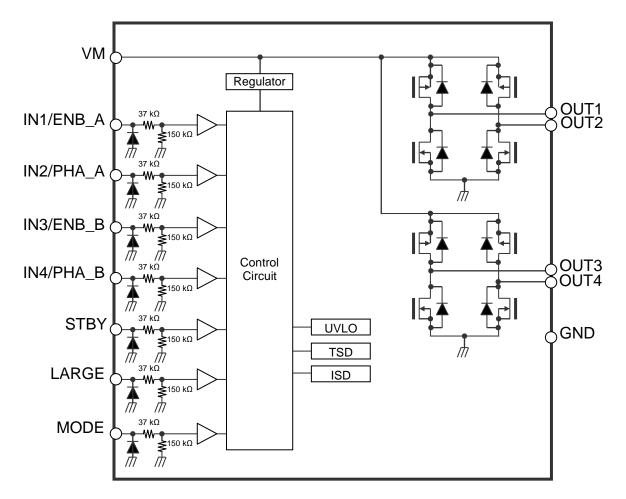


Pin Assignment (Top View)



Note: In DC Brushed motor Large mode (LARGE pin is set to High), pins OUT1 and OUT2 are connected as OUT+ pin and pins OUT3 and OUT4 pin are connected as OUT- pin. Then Large mode is controlled with IN1/ENB_A pin and IN2/PHA_A pins.

Block Diagram



Note: The block diagram, functional blocks or constants may be omitted or simplified for explanatory purposes.

Pin name	Pin number	Functional description	Remarks
IN4/PHA_B	1	Control input	Refer to the section of "Input/Output Functions".
IN3/ENB_B	2	Control input	Refer to the section of "Input/Output Functions".
NC	3	No connection	Please use this terminal open.
IN1/ENB_A	4	Control input	Refer to the section of "Input/Output Functions".
IN2/PHA_A	5	Control input	Refer to the section of "Input/Output Functions".
STBY	6	Control input	Refer to the section of "Input/Output Functions".
NC	7	No connection	Please use this terminal open.
GND	8	GND pin	—
OUT2	9	Output	Motor coil connection pin
OUT1	10	Output	Motor coil connection pin
OUT3	11	Output	Motor coil connection pin
OUT4	12	Output	Motor coil connection pin
GND	13	GND pin	—
VM	14	Power supply pin	Operating range is from 1.8 V to 7.5 V.
LARGE	15	Control input	Refer to the section of "Input/Output Functions".
MODE	16	Control input	Refer to the section of "Input/Output Functions".

Pin Functions

Input / Output Functions

MODE	LARGE	STBY	IN1/ ENB_A	IN2/ PHA_A	IN3/ ENB_B	IN4/ PHA_B	OUT1	OUT2	OUT3	OUT4	Mode
		Н	Н	L	Х	Х	Н	L	Х	Х	Forward
		Н	L	Н	Х	Х	L	н	Х	Х	Reverse
		Н	Х	Х	Н	L	Х	Х	Н	L	Forward
L	L	Н	Х	Х	L	Н	Х	Х	L	Н	Reverse
		Н	Н	Н	Н	Н	L	L	L	L	Short brake
		Н	L	L	L	L	OFF	OFF	OFF	OFF	Stop
		L	Х	Х	Х	Х	OFF	OFF	OFF	OFF	Standby

IN Input mode (MODE=L), in Small mode (LARGE=L)

Note: 2 H-Bridge can be programmed and operate simultaneously. Note: X are Don't Care.

IN Input mode (MODE=L), in Large mode (LARGE=H)

MODE	LARGE	STBY	IN1/ ENB_A	IN2/ PHA_A	IN3/ ENB_B	IN4/ PHA_B	OUT1	OUT2	OUT3	OUT4	Mode	
		Н	Н	L	Х	Х	Н	Н	L	L	Forward	
		Н	L	Н	Х	Х	L	L	Н	Н	Reverse	
L	Н	Н	Н	Н	Х	Х	L	L	L	L	Short brake	
		Н	L	L	Х	Х	OFF	OFF	OFF	OFF	Stop	
		L	Х	Х	Х	Х	OFF	OFF	OFF	OFF	Standby	

Note: X are Don't Care.

PHASE input mode (MODE=H) in Small mode (LARGE=L)

MODE	LARGE	STBY	IN1/ ENB_A	IN2/ PHA_A	IN3/ ENB_B	IN4/ PHA_B	OUT1	OUT2	OUT3	OUT4	Mode
		Н	Н	Н	Х	Х	Н	L	Х	Х	Forward
		Н	Н	L	Х	Х	L	н	Х	Х	Reverse
н		Н	Х	Х	Н	Н	Х	Х	Н	L	Forward
	Ľ	Н	Х	Х	Н	L	Х	Х	L	Н	Reverse
		Н	L	Х	L	Х	OFF	OFF	OFF	OFF	Stop
		L	Х	Х	Х	Х	OFF	OFF	OFF	OFF	Standby

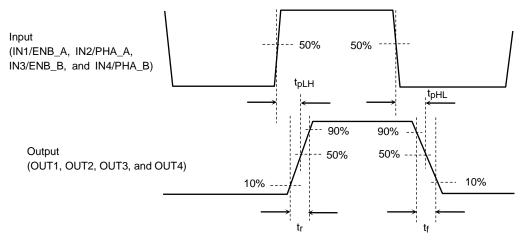
Note: 2 H-Bridge can be programmed and operate simultaneously. Note: X are Don't Care.

PHASE input mode (MODE=H), Large mode (LARGE=H)

MODE	LARGE	STBY	IN1/ ENB_A	IN2/ PHA_A	IN3/ ENB_B	IN4/ PHA_B	OUT1	OUT2	OUT3	OUT4	Mode
		Н	Н	Н	Х	Х	Н	Н	L	L	Forward
н	н	Н	Н	L	Х	Х	L	L	Н	Н	Reverse
	п	Н	L	Х	L	Х	OFF	OFF	OFF	OFF	Stop
		L	Х	Х	Х	Х	OFF	OFF	OFF	OFF	Standby

Note: X are Don't Care.

Timing Chart of Output Waveforms



Note: Timing charts may be simplified for explanatory purposes.

Symbol	Тур.	Unit
t _{pLH}	90	
t _{pHL}	90	20
tr	20	ns
t _f	10	

AC characteristics ($V_M = 3.0 V$, $T_a = 25^{\circ}C$)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	Remarks
Power supply voltage	Vм	8.0	V	—
Input voltage	Vin	-0.3 to 6	V	_
		4.0	А	In Large mode
Output ourrent	leur.	2.0	А	In Small mode
Output current	Ιουτ	5.0	А	In Large mode, Peak at 10 ms
		2.5	А	In Small mode, Peak at 10 ms
Output DMOS body diode	le.	2.0	А	In Small mode
forward current	lf	4.0	А	In Large mode
Power dissipation	PD	1.79	W	—
Operating range	Topr	-40 to 105	°C	—
Storage temperature	T _{stg}	-55 to 150	°C	_

Note: When mounted on the board (JEDEC 4 layers), if Ta exceeds 25°C, it is necessary to do the derating with 14.3mW/°C.

Back-EMF

While a motor is rotating, there is a timing at which power is fed back to the power supply. At that timing, the motor current recirculates back to the power supply due to the effect of the motor back-EMF. If the power supply does not have enough current sinking capability, the power supply and output pins of the device may rise above the rated voltage of 8.0 V. The magnitude of the motor back-EMF varies with usage conditions and motor characteristics. It must be fully verified that there is no risk that the device or other components will not be damaged or failed due to the motor back-EMF.

When the power is fed back to the power supply, the body diode of the output DMOS may turn on and a regenerative current may flow. At this time, the voltage applied to one of the output pins may become a negative value by the voltage of the body diode (V_f) . It is not a concern if the current of the body diode (I_f) is within the rated value (shown in above table) or less, it is no problem.

Over Current Detection (ISD) and Thermal Shutdown (TSD)

The ISD and TSD circuits are only intended to provide temporary protection against irregular conditions such as an output short-circuits; they do not necessarily guarantee the complete IC safety. If the device is used beyond the specified operating ranges, these circuits may not operate properly: then the device may be damaged due to an output short-circuit. The ISD circuit is only intended to provide a temporary protection against an output short-circuit. If such condition persists for a long time, the device may be damaged due to overstress. Overcurrent conditions must be removed immediately by external hardware.

IC Mounting

Do not insert devices incorrectly or in the wrong orientation. Otherwise, it may cause breakdown, damage and/or deterioration of the device.

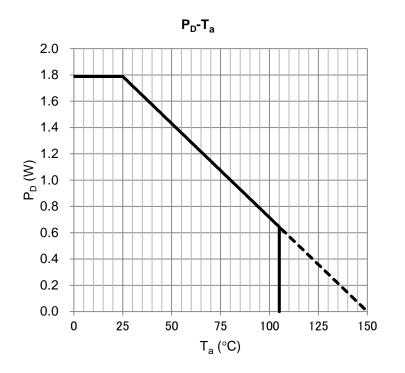
Characteristics	Symbol	Min	Тур.	Max	Unit	Remarks
Power supply voltage	VM	1.8	3.0	7.5	V	—
Output current	lout			4.0	А	In Large mode, $V_M = 5.0V$
Output current	IOUT	-	_	2.0	А	In Small mode, $V_M = 5.0V$
PWM frequency	fpwm	_	_	500	kHz	Duty=50%

Operating Conditions (Ta = -40 to 105°C)

Electrical Characteristics (Unless otherwise specified, VM = 1.8 to 7.0 V, Ta = 25°C)

Charac	teristics	Symbol	Test condition	Min	Тур.	Max	Unit	
Consumption current		ICC (W)	Forward / Reverse mode, $V_M = 3.0$ V, Output open	_	0.6	1.0	mA	
		ICC (STB)	Standby mode, $V_M = 3.0 V$	_	0	0.22	μA	
		VIH1	V _M = 1.8 V	1.5	_	5.5		
		V _{IH2}	V _M = 3.0 V	1.7	_	5.5		
	Input voltage	V _{IH3}	V _M = 5.0 V	2.0	_	5.5	V	
Control circuit		VIH4	V _M = 7.0 V	2.0	_	5.5		
		VIL	_	- 0.3	_	0.5		
	la su la suma si	Ιн	V _{IN} =3.0 V	10	16	22		
	Input current	١ _{IL}	_	_	_	1.0	μA	
	etween drain and	R _{ON(D-S)}	I_{OUT} = 1.0 A , V _M =5.0 V In Small mode	_	0.22	0.35	Ω	
	source of output transistor (Sum of upper and lower side)		$I_{OUT} = 1.0 \text{ A}$, $V_{M} = 5.0 \text{ V}$ In Large mode	_	0.11	0.175	Ω	
Output look	Output leakage current		V _M = 3.0 V	_	—	0.5		
Output lear			$V_{\rm M} = 3.0 V$	_	_	0.5	μA	
Output DMOS body diode forward voltage		Vf	$I_{\rm f} = 0.4$ A, $V_{\rm M} = 5.0$ V	_	0.7	1.0	V	

(Reference data) P_D - T_a Characteristics



When mounted on the board (JEDEC 4 layers)

Note: Characteristics shown above are reference values and not guaranteed.

Fault Detections

Thermal Shut Down (TSD)

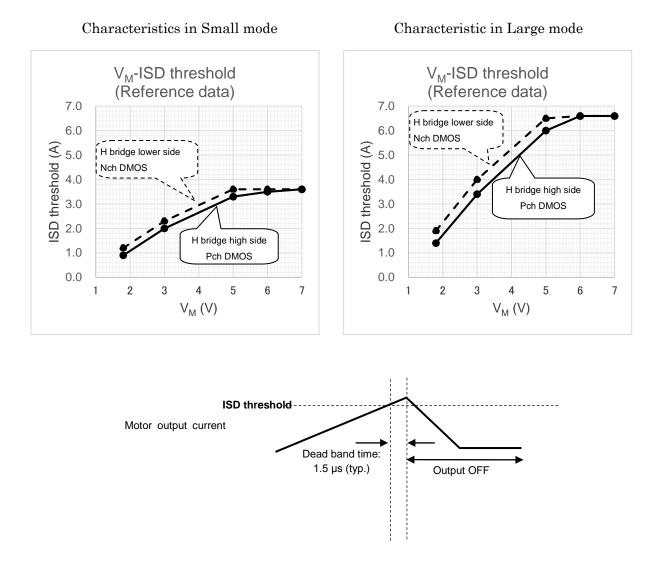
When the junction temperature (T_j) of the IC exceeds 170°C (typ.), all outputs are turned off. When the junction temperature (T_j) falls by 40°C (typ.) or more, it returns to the normal mode. Note: Above TSD operation and release thresholds are reference values, and are not guaranteed.

Over Current Detection (ISD)

When the IC detects an over current in the output transistors (exceeding ISD operation threshold value), all outputs are turned off. It has a dead band time of 1.5 μ s (typ.) to avoid ISD false triggering by switching noise. ISD releases when one of the followings occur:

1. Operation mode is re-configured after setting to the standby mode, set STBY to L then H.

2. Recycle the power supply.



Note: Above ISD operation threshold value and dead band time are reference values, and are not guaranteed.

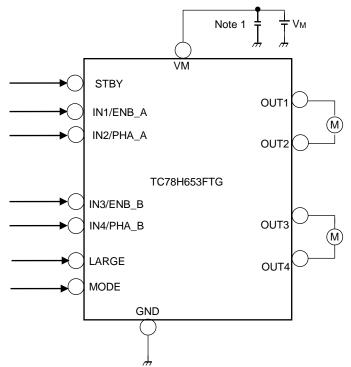
Under Voltage Lockout (UVLO)

When VM pin voltage falls to less than 1.7 V (typ.), all outputs are turned off. UVLO is released when VM pin voltage rises at or above 1.7 V (typ.).

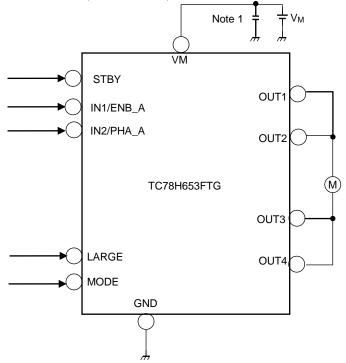
Note: Above UVLO operation and release thresholds are reference values, and are not guaranteed.

Examples of Application Circuit

In Small mode for two Brushed motors (LARGE = L)



In Large mode for one Brushed motor (LARGE = H)



- Note1: A power supply ceramics capacitor for noise absorption should be connected as close to the IC as possible.
- Note2: Utmost care is necessary in the design of V_M and GND line since the IC may be destroyed by short-circuiting between outputs, by short-circuiting to the power supply or ground, or by short-circuiting between contiguous pins.



Unit: mm

Package Dimensions

P-VQFN16-0303-0.50-001

3.0 A В 3.0 x4 \square S AB 0.1 0.9MAX 0.05MAX S 0.1 Ş 0.08 S \bigcirc 0.4±0.05 0.5 0.75TYP 1000 + 16 --0 Ć ---C 13 (1 O O D 12 9 0.25±0.05 S AB 0.1 \mathbb{O} \oplus 0.05 🕅 S 0.75TYP

Weight: 0.02 g (Typ.)

Notes on Contents

1. Block Diagrams

Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purposes.

2. Equivalent Circuits

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

3. Timing Charts

Timing charts may be simplified for explanatory purposes.

4. Application Circuits

The application circuits shown in this document are provided for reference purposes only. Thorough evaluation is required, especially at the mass production design stage.

Providing these application circuit examples does not grant a license for industrial property rights.

5. Test Circuits

Components in the test circuits are used only to obtain and confirm the device characteristics. These components and circuits are not guaranteed to prevent malfunction or failure from occurring in the application equipment.

IC Usage Considerations Notes on handling of ICs

- [1] The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings.Exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.
- [2] Use an appropriate power supply fuse to ensure that a large current does not continuously flow in case of over current and/or IC failure. The IC will fully break down when used under conditions that exceed its absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs from the wiring or load, causing a large current to continuously flow and the breakdown can lead smoke or ignition. To minimize the effects of the flow of a large current in case of breakdown, appropriate settings, such as fuse capacity, fusing time and insertion circuit location, are required.
- [3] If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design to prevent device malfunction or breakdown caused by the current resulting from the inrush current at power ON or the negative current resulting from the back electromotive force at power OFF. IC breakdown may cause injury, smoke or ignition. Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable the protection function may not energing IC breakdown IC breakdown may cause

unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.

[4] Do not insert devices in the wrong orientation or incorrectly.

Make sure that the positive and negative terminals of power supplies are connected properly.

Otherwise, the current or power consumption may exceed the absolute maximum rating, and exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.

In addition, do not use any device that is applied the current with inserting in the wrong orientation or incorrectly even just one time.

Points to remember on handling of ICs

(1) Thermal Shutdown Circuit

Thermal shutdown circuits do not necessarily protect ICs under all circumstances. If the thermal shutdown circuits operate against the over temperature, clear the heat generation status immediately.

Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the thermal shutdown circuit to not operate properly or IC breakdown before operation.

(2) Heat Radiation Design

In using an IC with large current flow such as power amp, regulator or driver, please design the device so that heat is appropriately radiated, not to exceed the specified junction temperature (T_J) at any time and condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, please design the device taking into considerate the effect of IC heat radiation with peripheral components.

(3) Back-EMF

When a motor rotates in the reverse direction, stops or slows down abruptly, a current flow back to the motor's power supply due to the effect of back-EMF. If the current sink capability of the power supply is small, the device's motor power supply and output pins might be exposed to conditions beyond absolute maximum ratings. To avoid this problem, take the effect of back-EMF into consideration in system design.

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